Complementary Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("1" Suffix)
- Electrically Similar to Popular TIP41 and TIP42 Series
- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings:
 - Human Body Model, 3B > 8000 V
 - Machine Model, C > 400 V
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Packages*



ON Semiconductor®

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SILICON POWER TRANSISTORS 6 AMPERES 100 VOLTS, 20 WATTS



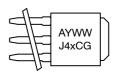


DPAK CASE 369C STYLE 1

DPAK-3 CASE 369D STYLE 1

MARKING DIAGRAMS





DPAK

DPAK-3

A = Assembly Location

′ = Year

WW = Work Week

J4xC = Device Code

x = 1 or 2

G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS

| Rating | Symbol | Max | Unit |
|---|-----------------------------------|---------------|-----------|
| Collector-Emitter Voltage | V _{CEO} | 100 | Vdc |
| Collector-Base Voltage | V _{CB} | 100 | Vdc |
| Emitter-Base Voltage | V _{EB} | 5 | Vdc |
| Collector Current Continuous Peak | I _C | 6 10 | Adc |
| Base Current | I _B | 2 | Adc |
| Total Power Dissipation @ T _C = 25°C Derate above 25°C | P _D | 20 0.16 | W W/°C |
| Total Power Dissipation (Note 1) @ T _A = 25°C Derate above 25°C | P _D | 1.75 0.014 | W W/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -65 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------|------|------|
| Thermal Resistance, Junction-to-Case | $R_{	heta JC}$ | 6.25 | °C/W |
| Thermal Resistance, Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 71.4 | °C/W |

^{1.} These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|-----------------------|----------|---------|------|
| OFF CHARACTERISTICS | | | | |
| Collector–Emitter Sustaining Voltage (Note 2) $(I_C = 30 \text{ mAdc}, I_B = 0)$ | V _{CEO(sus)} | 100 | - | Vdc |
| Collector Cutoff Current (V _{CE} = 60 Vdc, I _B = 0) | I _{CEO} | - | 50 | μAdc |
| Collector Cutoff Current (V _{CE} = 100 Vdc, V _{EB} = 0) | Ices | - | 10 | μAdc |
| Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0) | I _{EBO} | - | 0.5 | mAdc |
| ON CHARACTERISTICS (Note 2) | | | | |
| DC Current Gain (I _C = 0.3 Adc, V _{CE} = 4 Vdc) (I _C = 3 Adc, V _{CE} = 4 Vdc) | h _{FE} | 30 15 | - 75 | |
| Collector–Emitter Saturation Voltage (I _C = 6 Adc, I _B = 600 mAdc) | V _{CE(sat)} | - | 1.5 | Vdc |
| Base-Emitter On Voltage (I _C = 6 Adc, V _{CE} = 4 Vdc) | V _{BE(on)} | - | 2 | Vdc |
| DYNAMIC CHARACTERISTICS | | | | |
| Current Gain – Bandwidth Product (Note 3) (I_C = 500 mAdc, V_{CE} = 10 Vdc, f_{test} = 1 MHz) | f _T | 3 | - | MHz |
| Small–Signal Current Gain ($I_C = 0.5$ Adc, $V_{CE} = 10$ Vdc, $f = 1$ kHz) | h _{fe} | 20 | _ | |

^{2.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

ORDERING INFORMATION

| Device | Package Type | Package | Shipping [†] |
|--------------|---------------------|---------|-----------------------|
| MJD41CRLG | DPAK (Pb-Free) | 369C | 1,800 / Tape & Reel |
| MJD41CT4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel |
| NJVMJD41CT4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel |
| MJD42CG | DPAK (Pb-Free) | 369C | 75 Units / Rail |
| MJD42C1G | DPAK-3 (Pb-Free) | 369D | 75 Units / Rail |
| MJD42CRLG | DPAK (Pb-Free) | 369C | 1,800 / Tape & Reel |
| NJVMJD42CRLG | DPAK (Pb-Free) | 369C | 1,800 / Tape & Reel |
| MJD42CT4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel |
| NJVMJD42CT4G | DPAK (Pb-Free) | 369C | 2,500 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{3.} $f_T = |h_{fe}| \cdot f_{test}$.

TYPICAL CHARACTERISTICS

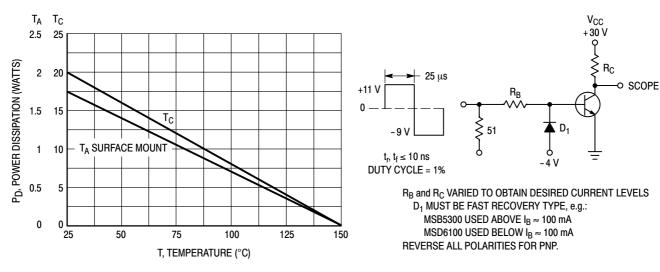


Figure 1. Power Derating

Figure 2. Switching Time Test Circuit

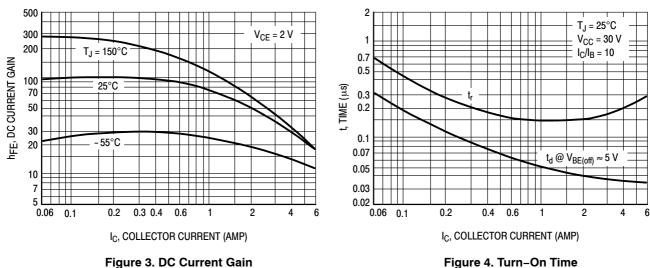


Figure 3. DC Current Gain

 $T_J = 25^{\circ}C$ $T_{.I} = 25^{\circ}C$ 3 $V_{CC} = 30 \text{ V}$ 1.6 2 $I_C/I_B = 10$ $I_{B1} = I_{B2}$ 1.2 t, TIME (µs) 0.7 0.5 0.8 $V_{CE(sat)} @ I_C/I_B = 10$ 0.3 0.2 $V_{BE} @ V_{CE} = 4 V$ 0.4 0.1 $V_{BE(sat)} @ I_C/I_B = 10$ 0.07 0.05 0.06 0.1 0.2 0.3 0.4 0.6 0.06 0.1 0.4 0.6 6 IC, COLLECTOR CURRENT (AMP) IC, COLLECTOR CURRENT (AMP) Figure 5. "On" Voltages Figure 6. Turn-Off Time

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V, VOLTAGE (VOLTS)

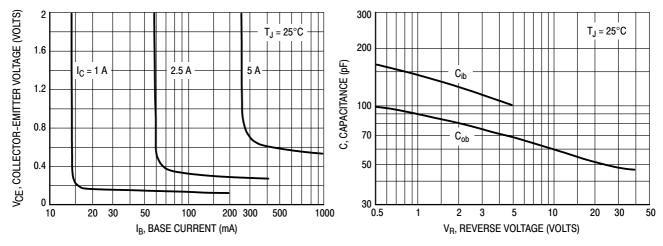


Figure 7. Collector Saturation Region

Figure 8. Capacitance

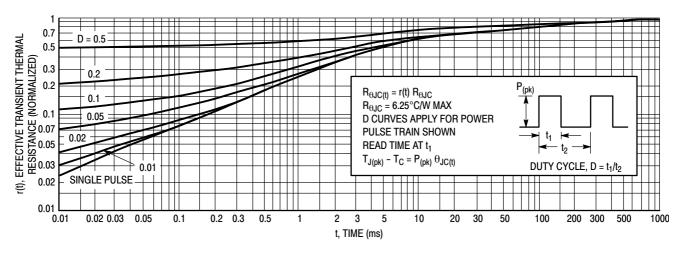


Figure 9. Thermal Response

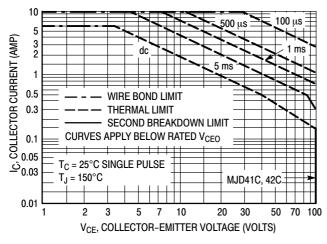


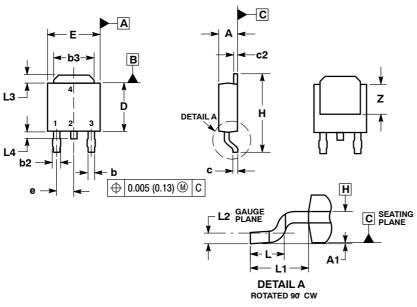
Figure 10. Maximum Forward Bias Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C – V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 10 is based on $T_{J(pk)} = 150^{\circ} C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^{\circ} C$. $T_{J(pk)}$ may be calculated from the data in Figure 9. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

PACKAGE DIMENSIONS

DPAK CASE 369C-01 ISSUE D

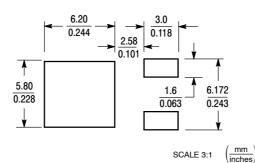


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
 2. CONTROLLING DIMENSION: INCHES.
- THERMAL PAD CONTOUR OPTIONAL WITHIN DI-MENSIONS b3, L3 and Z.
- MENSIONS DS., LS BITUZ...
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
- DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
- 6. DATUMS A AND B ARE DETERMINED AT DATUM PI ANF H

| _ | | | | | |
|-----|-----------|-------|-------------|-------|--|
| | INCHES | | MILLIMETERS | | |
| DIM | MIN | MAX | MIN | MAX | |
| Α | 0.086 | 0.094 | 2.18 | 2.38 | |
| A1 | 0.000 | 0.005 | 0.00 | 0.13 | |
| b | 0.025 | 0.035 | 0.63 | 0.89 | |
| b2 | 0.030 | 0.045 | 0.76 | 1.14 | |
| b3 | 0.180 | 0.215 | 4.57 | 5.46 | |
| O | 0.018 | 0.024 | 0.46 | 0.61 | |
| c2 | 0.018 | 0.024 | 0.46 | 0.61 | |
| D | 0.235 | 0.245 | 5.97 | 6.22 | |
| Е | 0.250 | 0.265 | 6.35 | 6.73 | |
| ø | 0.090 BSC | | 2.29 BSC | | |
| Ξ | 0.370 | 0.410 | 9.40 | 10.41 | |
| ٦ | 0.055 | 0.070 | 1.40 | 1.78 | |
| L1 | 0.108 REF | | 2.74 | REF | |
| L2 | 0.020 BSC | | 0.51 BSC | | |
| LЗ | 0.035 | 0.050 | 0.89 | 1.27 | |
| L4 | | 0.040 | | 1.01 | |
| Z | 0.155 | | 3.93 | | |

SOLDERING FOOTPRINT*



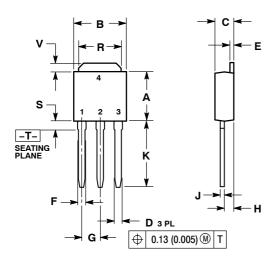
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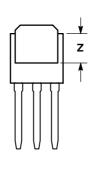
STYLE 1: PIN 1. BASE 2. COLLECTOR

- 3. EMITTER 4. COLLECTOR

PACKAGE DIMENSIONS

IPAK CASE 369D-01 ISSUE C





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

| | INCHES | | MILLIN | ETERS |
|-----|-----------|-------|----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.235 | 0.245 | 5.97 | 6.35 |
| В | 0.250 | 0.265 | 6.35 | 6.73 |
| С | 0.086 | 0.094 | 2.19 | 2.38 |
| D | 0.027 | 0.035 | 0.69 | 0.88 |
| E | 0.018 | 0.023 | 0.46 | 0.58 |
| F | 0.037 | 0.045 | 0.94 | 1.14 |
| G | 0.090 BSC | | 2.29 BSC | |
| Н | 0.034 | 0.040 | 0.87 1.0 | |
| J | 0.018 | 0.023 | 0.46 | 0.58 |
| K | 0.350 | 0.380 | 8.89 | 9.65 |
| R | 0.180 | 0.215 | 4.45 | 5.45 |
| S | 0.025 | 0.040 | 0.63 | 1.01 |
| ٧ | 0.035 | 0.050 | 0.89 | 1.27 |
| Z | 0.155 | | 3.93 | |

STYLE 1:

PIN 1. BASE

- 2. COLLECTOR
- 3 FMITTER
- 4. COLLECTOR

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